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S B F

** CONTINUING DATA *****

This application is a DIV of 10/005,355 12/07/2001 PAT 6,710,383

S B F

** FOREIGN APPLICATIONS *****

JAPAN 2000-375610 12/11/2001

S B F

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Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY	SHEETS DRAWING	TOTAL CLAIMS	INDEPENDENT CLAIMS
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	JAPAN	7	12	2
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METHOD OF MAKING A MISFET SEMICONDUCTOR DEVICE HAVING
 TITLE A HIGH DIELECTRIC CONSTANT INSULATING FILM WITH
 Semiconductor device and process for producing the same. TAPERED END PORTIONS

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of
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